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Last Name = SAKURADA First Name = MASAHIRO

Application#||Patent#||Status||Date Filed||Title **Inventor Name** 08498894 5609682l 150 |07/06/1995||A METHOD FOR THE SAKURADA, PREPARATION OF SILICON MASAHIRO SINGLE CRYSTAL 11/30/1995 METHOD FOR THE 08565100 5667584|| 150 SAKURADA, PREPARATION OF A SINGLE MASAHIRO CRYSTAL OF SILICON WITH DECREASED CRYSTAL DEFECTS 08655810 5817171 150 05/31/1996 APPARATUS AND METHOD SAKURADA, FOR PRODUCING SINGLE MASAHIRO CRYSTAL USING CZOCHRALSKI TECHNIQUE 08660198 5728211 250 ||06/03/1996||SILICON SINGLE CRYSTAL SAKURADA, WITH LOW DEFECT MASAHIRO DENSITY AND METHOD OF PRODUCING SAME 08666654 5704973 150 |06/18/1996||AN APPARATUS AND SAKURADA, METHOD FOR THE UNIFORM MASAHIRO DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL |5730800|| 150 08768282 |12/17/1996||FUSED SILICA GLASS SAKURADA, CRUCIBLE MASAHIRO 08798472 5948163 250 02/10/1997||APPARATUS FOR SAKURADA, MANUFACTURING MASAHIRO CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD

06/04/1998||METHOD FOR PRODUCING A ||SAKURADA,

SINGLE CRYSTAL USING

MASAHIRO

				CZOCHRALSKI TECHNIQUE	
09125339	6071337	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	SAKURADA, MASAHIRO
09232561	6174364	150	01/15/1999	METHOD FOR PRODUCING SILICON MONOCRYSTAL AND SILICON MONOCRYSTAL WAFER	SAKURADA, MASAHIRO
09328278	6190452	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
09646713	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBTRATE FOR EPITAXIAL SILICON WAFER	SAKURADA, MASAHIRO
09727275	6482260	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
10204935	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
10312921	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	SAKURADA, MASAHIRO
10500580	7129123	150	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	SAKURADA, MASAHIRO
10512470	7294196	150	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
10516347	7258744	150	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SAKURADA, MASAHIRO
10530557	Not	95	04/07/2005	ANNEALED WAFER AND	SAKURADA, ·

	Issued			METHOD FOR MANUFACTURING THE SAME	MASAHIRO
10538878	7214268	150	06/14/2005	METHOD OF PRODUCING P- DOPED SILICON SINGLE CRYSTAL AND P-DOPED N- TYPE SILICON SINGLE CRYSTAL WAFER	SAKURADA, MASAHIRO
10542376	Not Issued	71	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	SAKURADA, MASAHIRO
10546693	Not Issued	61	1		SAKURADA, MASAHIRO
10560581	Not Issued	71		1 0 0	SAKURADA, MASAHIRO
10561205	Not Issued	93	02/03/2006		SAKURADA, MASAHIRO
10561865	7226507	150	02/20/2006	METHOD FOR PRODUCING SINGLE CRYSTAL AND SINGLE CRYSTAL	SAKURADA, MASAHIRO
11664436	Not Issued	20	03/30/2007	Apparatus for Producing a Single Crystal	SAKURADA, MASAHIRO

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